



TOYO LED ELECTRONICS LIMITED

Room 1610, Hong Kong Plaza, 188 Connaught Road West, Hong Kong.

Tel: (852) 2540 7288

Fax: (852) 2517 1797

<http://www.toyo-led.com>

email: sales@toyo-led.com



CODE BL

Chip Material: InGaN Blue LED Chip



ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

PARAMETER	SYMBOL	MAXIMUM RATING	UNIT
Power Dissipation	P _D	96	mW
Peak Forward Current (1/10 Duty Cycle, 0.1 Ms Pulse Width)	I _{PEAK}	100	mA
DC Forward Current	I _F	30	mA
Reverse Voltage	V _R	5	V
Operating Temperature Range	T _A	-40°C to +85°C	
Storage Temperature Range	T _{STG}	-40°C to +85°C	
Solder temperature 1/16 inch below seating plane for 3 seconds at 260°C			

ELECTRICAL OPTICAL CHARACTER AND CURVES (Ta = 25°C)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT	LOCATION	TEST CONDITION
Forward Voltage	V _F	-	3.00	3.20	V	Per Chip	I _F = 20mA
Luminous Intensity	I _v	42.0	46.0	50.0	mcd	Per Chip	I _F = 20mA
Peak Emission Wavelength	λ _p	-	472	-	nm	Per Chip	I _F = 20mA
Dominant Emission Wavelength	λ _d	465	470	475	nm	Per Chip	I _F = 20mA
Spectral Line Half-Width	Δλ _{1/2}	-	25	-	nm	Per Chip	I _F = 20mA
Capacitance	C	-	100	-	pF	Per Chip	V _F = 0V; f = 1MHz
Reverse Current	I _R	-	-	10	uA	Per Chip	V _R = 5V

Note:

- Luminous intensity tolerance is ±10%;**
- Dominant Emission Wavelength tolerance is ±5%.**



CODE BL

■ Typical Electro-Optical Characteristic Curve:

FIG. 1 Forward Current Vs. Forward Voltage

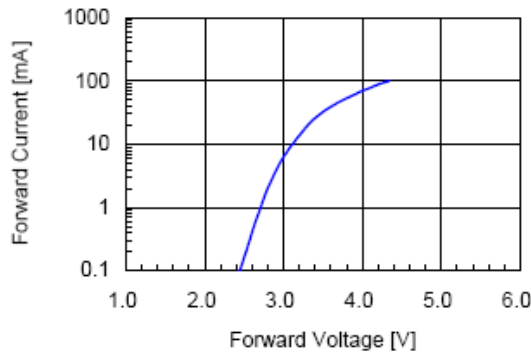


FIG. 2 Relative Intensity Vs. Forward Current

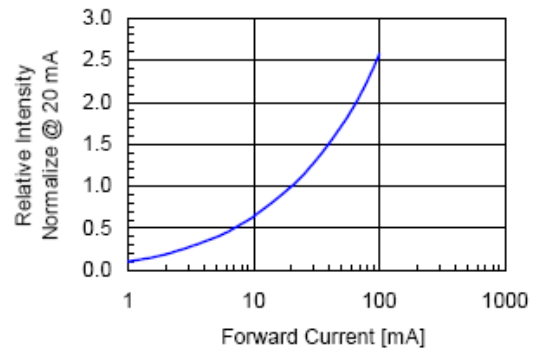


FIG. 3 Forward Voltage Vs. Temperature

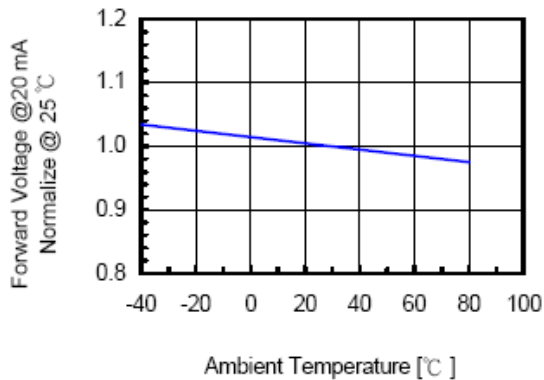


FIG. 4 Relative Intensity Vs. Temperature

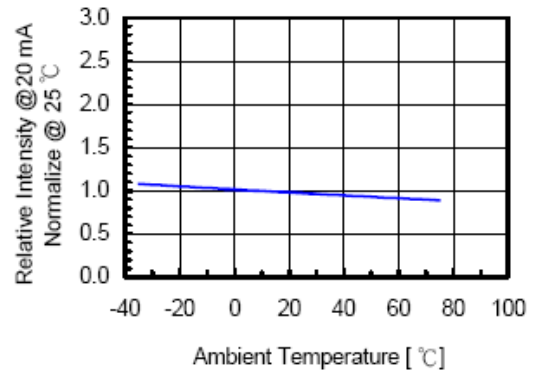


FIG. 5 Relative Intensity Vs. Wavelength

